# **EXAMINATION NO. 3** (Average score = 74/100)

# Problem 1 - (25 points)

Referring to the feedback circuit shown on the right, answer and/or fill in the blanks of the following questions:

a. What kind of mixing is being employed?

<u>Series</u>  $\rightarrow$  ( $V_{in} - V_{out}$ )

b. What kind of sampling is being employed?

<u>Shunt  $\rightarrow$  ( $V_{out}$  via mn1's CG gain stage))</u>

c. What type of amplifier is the feedback circuit?

<u>V<sub>out</sub> / V<sub>in</sub> → Voltage Amplifier</u>

d.  $R_{in} = R_{in_{open_{loop}}} * (1 + LoopGain)$ 

e.  $R_{out} = R_{out\_open\_loop} * \_ 1 \div (1 + LoopGain)$ 

f. Calculate the loop gain of this circuit (assume  $r_{ds} \rightarrow \infty$  and derive the relationship as a function of small-signal parameters, R, and  $A_v$ ) –hint: break the loop somewhere and compute the transfer function–.

## Opening the loop at the gate of mn2:

$$LG = (v_{d2} / v_{g2}) (v_{d1} / v_{s1}) (v_{g2}' / v_{d1}) = (CS \text{ gain}) (CG \text{ gain}) (A_v)$$
$$= (-g_{m2}/g_{m1}) (g_{m1}R) (A_v) = -g_{m2}RA_v$$



#### Problem 2 - (25 points)

Referring to the circuit shown, determine the closed-loop  $V_{\text{out}}$  output resistance  $R_{\text{out}}$  using Return-Ratio (RR) and Blackman's formula:

$$R_{out} = \underline{R_{out}}_{(Controlled Source Gain=0)} \times (1 + \underline{RR}_{output port shorted})$$

$$(1 + \underline{RR}_{output port open})$$

(Assume  $r_{ds} \rightarrow \infty$ ,  $R_i$ ,  $R_o$ , and  $A_v$  are the input resistance, the output resistance, and the gain of the differential amplifier. Derive the relationship as a function of small-signal parameters,  $R_1$ ,  $R_2$ , and  $A_v$ .)

### <u>Solution</u>

For RR (Loop Gain), break the loop at the gate of mn1:

 $RR_{output port shorted} = 0$  (amplifier  $A_v$  amplifies a "0" signal)

 $RR_{output \text{ port open}} = (v_{s1} / v_{g1}) (v_{l} / v_{s1}) (v_{g1}' / v_{l}) = (CD \text{ gain}) (Voltage divider) (A_v)$ 

$$= \frac{g_{m1}(R_1 || [R_i + R_2])}{1 + g_{m1}(R_1 || [R_i + R_2])} \cdot \frac{R_i}{R_i + R_2} \cdot A_v$$

 $\mathbf{R}_{\text{out-(Controlled Source Gain=0)}} = (1/g_{m1}) \parallel \mathbf{R}_1 \parallel (\mathbf{R}_2 + \mathbf{R}_I)$ 

=  $R_{out\_open\_loop}$  (open loop at gate of mn1)

Thus:

$$\mathbf{R}_{out} = \frac{(1/g_{m1}) || \mathbf{R}_{1} || (\mathbf{R}_{i} + \mathbf{R}_{2})}{\left[1 + \frac{g_{m1}(\mathbf{R}_{1} || [\mathbf{R}_{i} + \mathbf{R}_{2}])}{1 + g_{m1}(\mathbf{R}_{1} || [\mathbf{R}_{i} + \mathbf{R}_{2}])} \cdot \frac{\mathbf{R}_{i}}{\mathbf{R}_{i} + \mathbf{R}_{2}} \cdot \mathbf{A}_{v}\right]}$$



voltage amplifier А using feedback around current а In this amplifier is shown. problem assume all of the NMOS transistors are identical. Assume that  $R_1$  is greater than the transistor transconductance and find the input resistance,  $R_{in}$ , the resistance,  $R_{out}$ , the output voltage gain,  $v_{out}/v_{in}$ , and the  $v_{in}$ gainbandwidth (GB) in Hz. Assume that the output resistance this connected to voltage amplifier is large.



#### <u>Solution</u>

$$R_{in} \approx R_1 = \underline{10k\Omega}$$

$$R_{out} = \frac{v_t}{i_t}, \quad i_t = 2\frac{v_{out}}{R_2} = 2\frac{v_t}{R_2} \implies R_{out} = \frac{v_t}{i_t} = \frac{200k\Omega}{2} = \underline{100k\Omega}$$
$$\overline{v_{in}} \approx \frac{v_{in}}{R_1} + \frac{v_{out}}{R_2} \quad \text{and} \quad i_{out} \approx -\frac{v_{out}}{R_2}$$

Since  $i_{in} = i_{out}$ , we get

$$\frac{v_{in}}{R_1} + \frac{v_{out}}{R_2} = -\frac{v_{out}}{R_2} \longrightarrow \frac{v_{in}}{R_1} = -2\frac{v_{out}}{R_2} \longrightarrow \frac{v_{out}}{v_{in}} = -\frac{R_2}{2R_1} = -10V/V$$

The dominant pole is found as,

$$p_{dominant} = \frac{1}{R_{out}C_{out}} = \frac{1}{100k\Omega \cdot 0.1\text{pF}} = 100\text{x}10^6 \text{ rads/sec.}$$

 $\therefore \quad GB = 10 \cdot 100 \times 10^6 \text{ rads/sec.} = 1000 \times 10^6 \text{ rads/sec.} \rightarrow \quad GB = \underline{159.15 \text{ MHz}}$ 

Note: Many tried to work this problem as a feedback problem (which it is) so the results would be achieved from a shunt-shunt feedback network as follows.

The feedback factor would be  $f = -1/R_2$  and the amplifier gain would be

$$a = \frac{v_{out}}{i_{in}} = -R_2$$
 (loop gain is 1)

Therefore the closed loop gain would be

$$\frac{v_{out}}{i_{in}} = \frac{a}{1+af} = \frac{-R_2}{2}$$

The desired voltage gain would be

$$\frac{v_{out}}{v_{in}} = \frac{v_{out}}{i_{in}} \frac{1}{R_{in}} = -\frac{R_2}{2R_1} = -\frac{10V/V}{2R_1}$$

The input resistance of the current amplifier is approximately zero, so feedback would give the correct input and output resistances calculated above.

# Problem 4 - (25 points)

A differential CMOS amplifier using depletion mode  $V_{DD}$ input devices is shown. Assume that the normal M3 0µm/1µm MOSFETs parameters are  $K_N$ ' =110V/ $\mu$ A<sup>2</sup>,  $V_{TN}$  = V<sub>BiasP</sub> 0.7V,  $\lambda_N = 0.04 \text{V}^{-1}$  and for the PMOS transistors  $v_{out}$ are  $K_P$ ' =110V/ $\mu$ A<sup>2</sup>,  $V_{TP}$  = 0.7V,  $\lambda_P$  =0.04V<sup>-1</sup>. V2 For the depletion mode NMOS transistors, the 100µm/1µm parameters are the same as the normal NMOS except that  $V_{TN} = -0.5$ V. (a.) What is the maximum input common-mode voltage, 100uA **V**BiasN  $V_{icm}^{+}(\max)$ ? (b.) What is the minimum input 00µm/1µm common-mode voltage,  $V_{icm}$  (min)? (c.) What S02FEP8 value of  $V_{DD}$  gives an  $ICMR = 0.5V_{DD}$ ?

<u>Solution</u>

(a.) 
$$V_{icm}^{+}(\max) = V_{DD} - V_{SD3}(\operatorname{sat}) - V_{DS1}(\operatorname{sat}) + V_{GS1}(50\mu\text{A})$$
  
 $i_D = \frac{\beta}{2} (V_{GS1} - V_{T1})^2 \rightarrow V_{GS1} = \sqrt{\frac{2i_D}{\beta}} + V_{T1} = V_{DS1}(\operatorname{sat}) + V_{T1}$   
 $\therefore V_{icm}^{+}(\max) = V_{DD} - V_{SD3}(\operatorname{sat}) + V_{T1} = V_{DD} - \sqrt{\frac{2I_{D3}}{\beta_3}} + V_{T1}$   
 $V_{icm}^{+}(\max) = V_{DD} - 0.3015 - 0.5 = \underline{V_{DD}} - 0.8015$   
(b.)  $V_{icm}^{-}(\min) = V_{DS5}(\operatorname{sat}) + V_{GS1}(50\mu\text{A}) = V_{DS5}(\operatorname{sat}) + V_{DS1}(\operatorname{sat}) + V_{T1}$   
 $V_{icm}^{-}(\min) = \sqrt{\frac{2I_{D5}}{\beta_5}} + \sqrt{\frac{2I_{D1}}{\beta_1}} + V_{T1} = 0.1348 + 0.0953 - 0.5 = \underline{-0.2698V}$ 

(c.) 
$$ICMR = V_{icm}^{+}(\max) - V_{icm}^{-}(\min) = V_{DD} - 0.8015 + 0.2698 = V_{DD} - 0.5317$$

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$$V_{DD} - 0.5317 = 0.5V_{DD} \rightarrow V_{DD} = 2(0.5317) = 1.063V$$